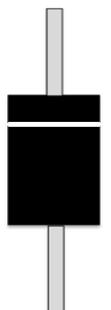


## Trench MOS Barrier Schottky Rectifier

**DO-201AD**
**TSA5V45**


### Features

- Advanced trench technology
- Low forward voltage drop
- Low power losses
- High efficiency operation
- Lead Free Finish, RoHS Compliant

### Applications

- DC/DC Converters
- AC/DC Adaptors
- Switching Power Supplies
- Freewheeling Diodes

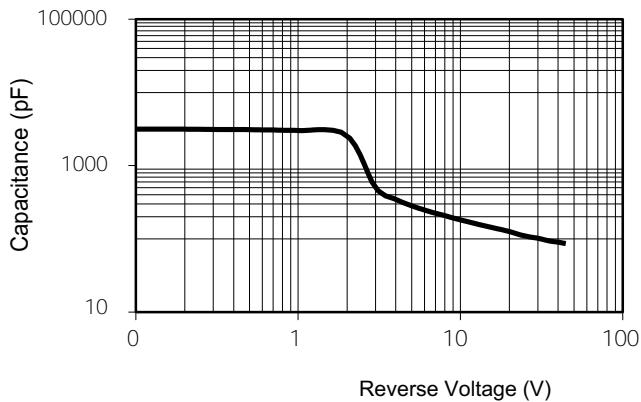
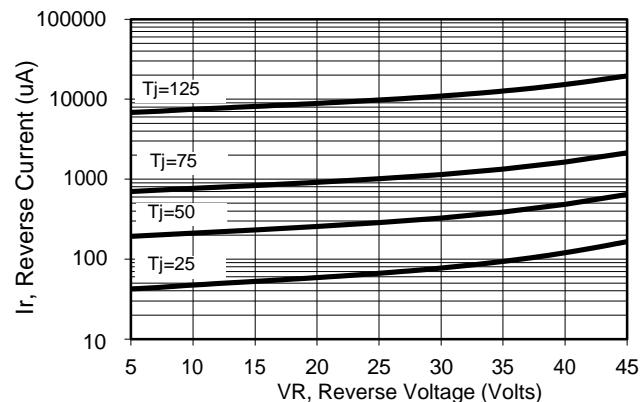
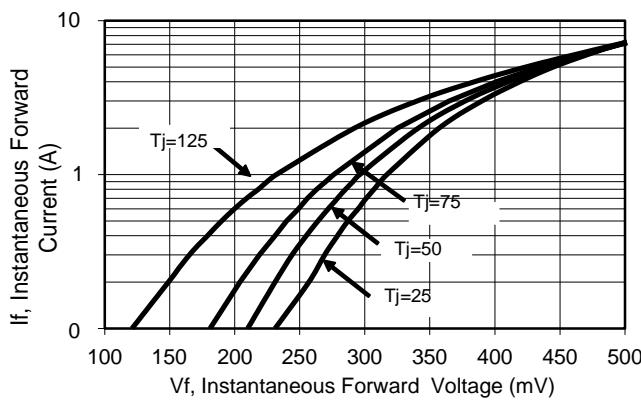
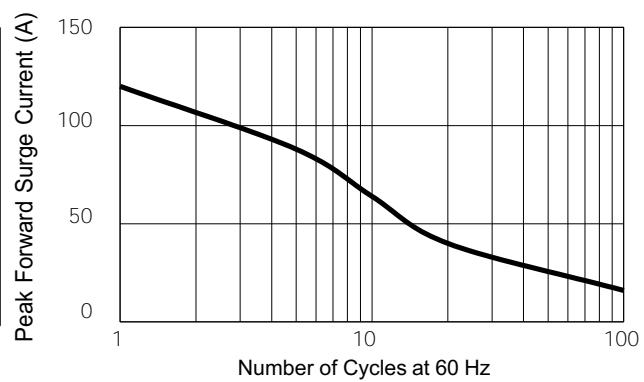
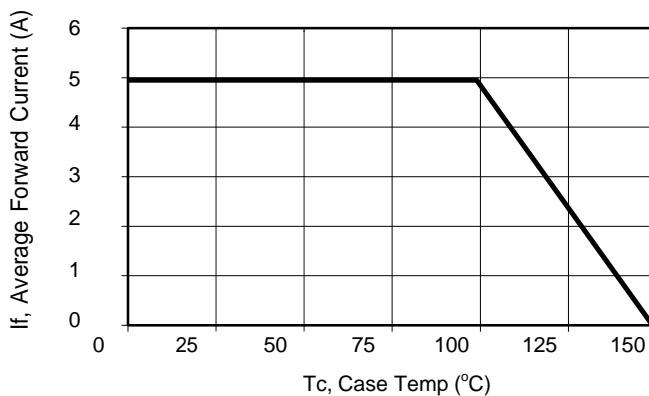
### Maximum ratings and electrical characteristics ( $T_J = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit		Unit
Maximum repetitive peak reverse voltage	VRRM	45		V
Maximum average forward rectified current	IF(AV)	5		A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	IFSM	120		A
Operating junction and storage temperature range	$T_J$ , TSTG	-50 to +150		°C
Typical thermal resistance per leg	DO-201AD	R <sub>JC</sub>	22	°C/W
Instantaneous forward voltage per diode	IF=5A	$T_J=25^\circ\text{C}$	TYP.	MAX.
			0.47	0.50
	IF=5A	$T_J=125^\circ\text{C}$	0.42	-
Instantaneous reverse current per diode at rated reverse voltage		$T_J=25^\circ\text{C}$	IR(2)	80 uA
		$T_J=125^\circ\text{C}$		- 10 mA

Notes:

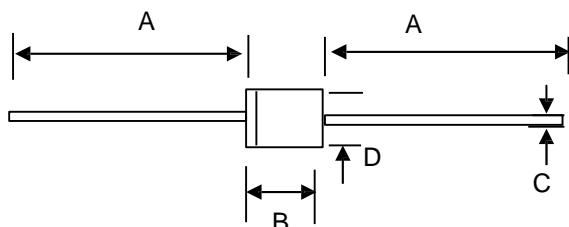
(1) Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

**RATINGS AND CHARACTERISTICS CURVES** ( $TA = 25^\circ\text{C}$  unless otherwise noted)


## PACKAGE OUTLINE DIMENSIONS

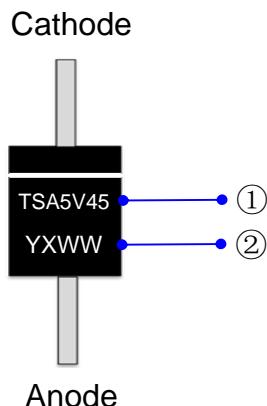
### DO-201AD



DO-201AD mechanical data

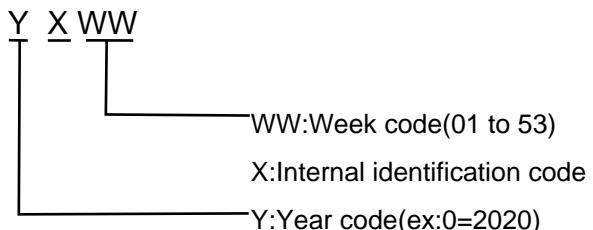
UNIT		A	B		D
mm	max	26.5	9.5	4	5.3
	min	24.5	7.3	1	4.8
mil	max	1043.30	374.01		208.67
	min	946.57	287.40		188.97

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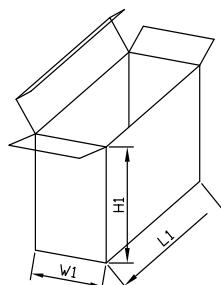
①Product model : TSA5V45

②PDC information

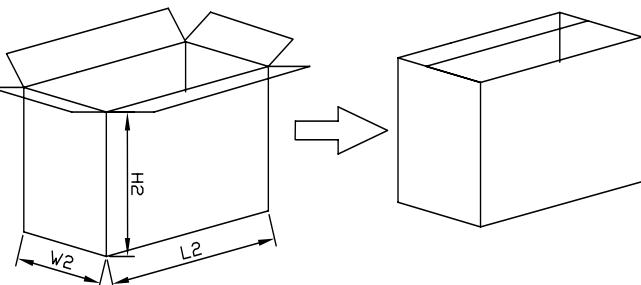


## Packaging Information

1.Inside Box



2.Outside Box



## Packaging Information

NO	UNIT	Inside Box			Outside Box		
Size	mm	L1	W1	H1	L2	W2	H2
		255	75	1115	415	280	320
QTY	PCS	Smallest package,1000PCS/carton			10,000PCS/carton,10 boxes in total		
Note	Tolerance	20mm,±3mm; 21-100mm,±5mm;			101-500mm,±10mm		